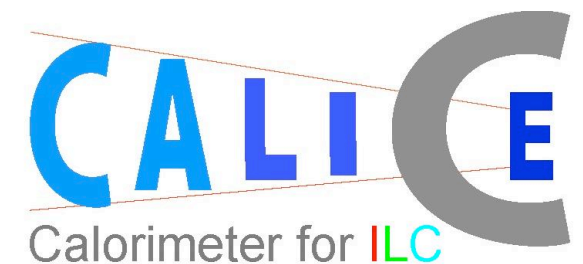


Characterising SiPMs for the Analogue Hadronic Calorimeter for the ILC

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On Behalf of the CALICE Collaboration



10 years
KIRCHHOFF-
INSTITUTE
FOR PHYSICS

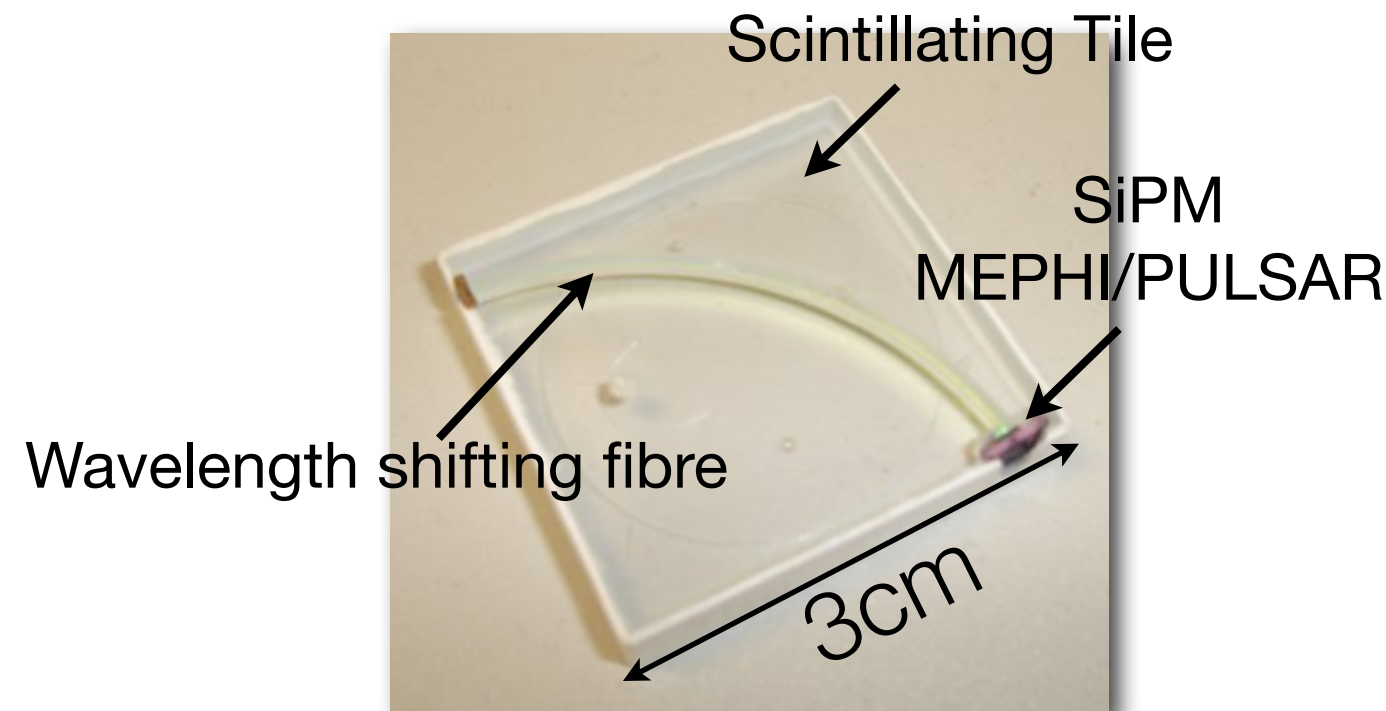
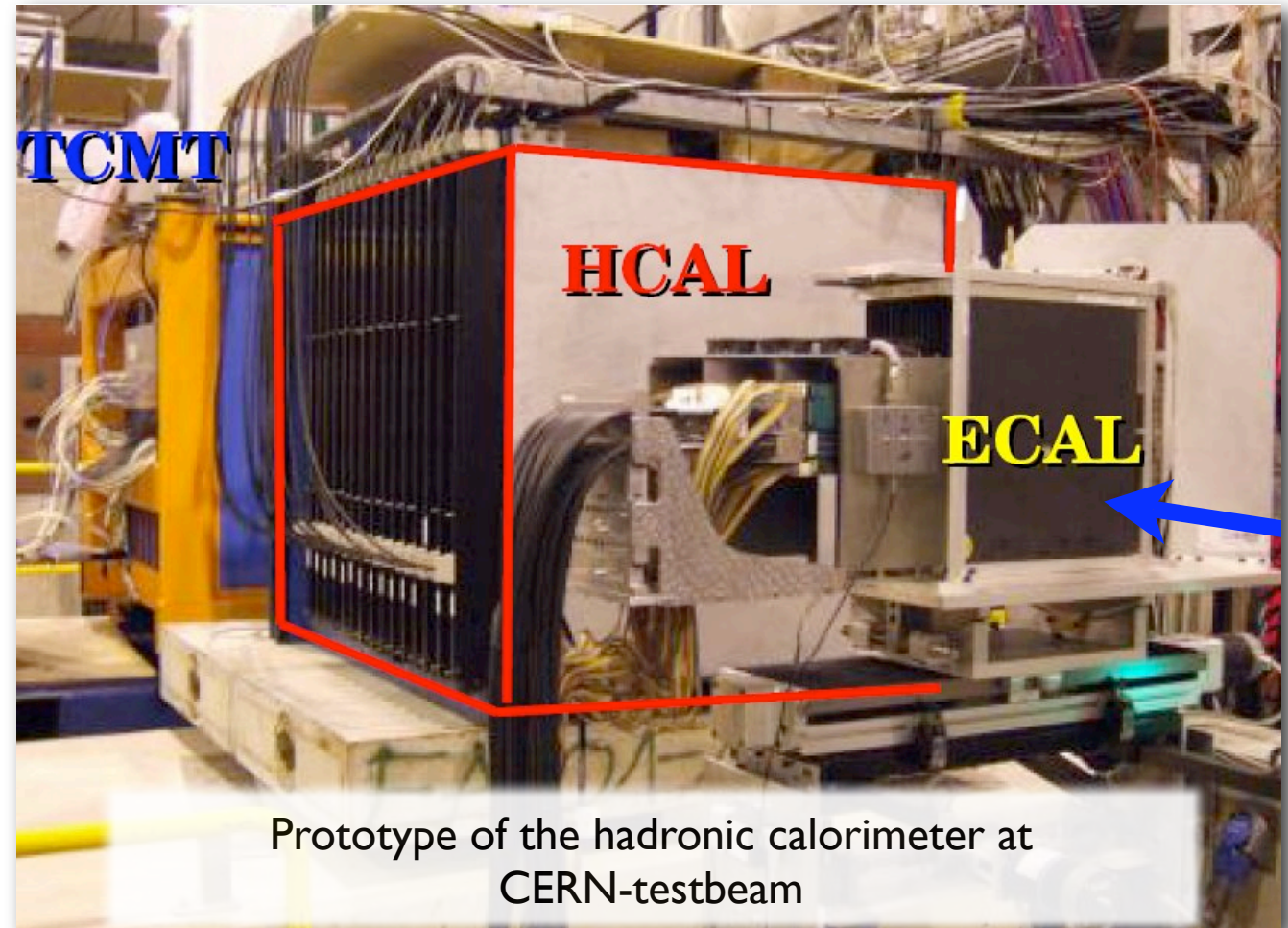


Outline

- **Analogue Hadronic Calorimeter (AHCAL) for the ILC**
- **Silicon Photomultiplier (SiPM) Introduction**
- **Essential SiPM Characterisation**
 - Photon Detection Efficiency
- **SiPM Readout Chip**
- **Tile Coupling Studies**
- **Development of Embedded LED Calibration System**

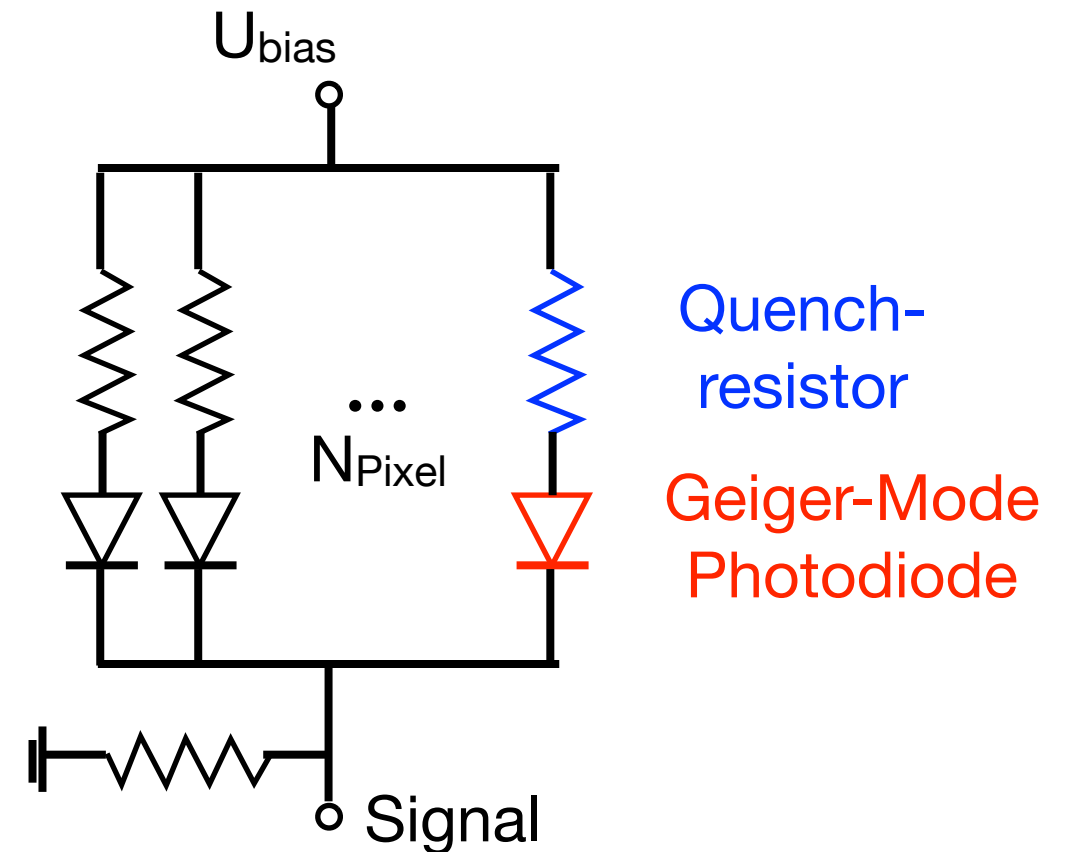
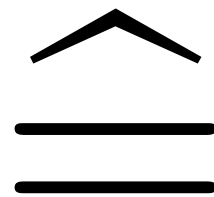
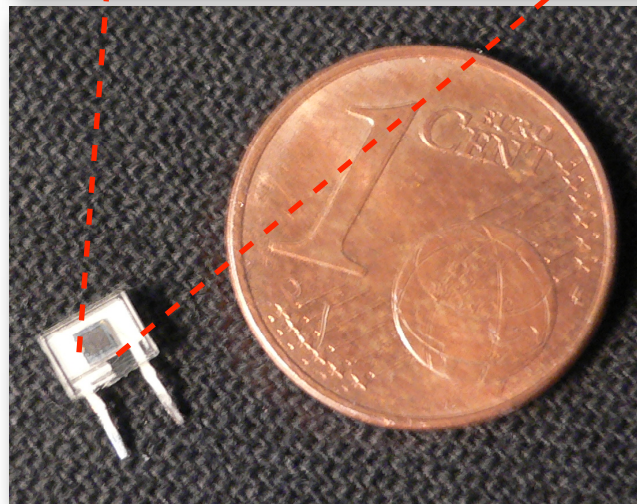
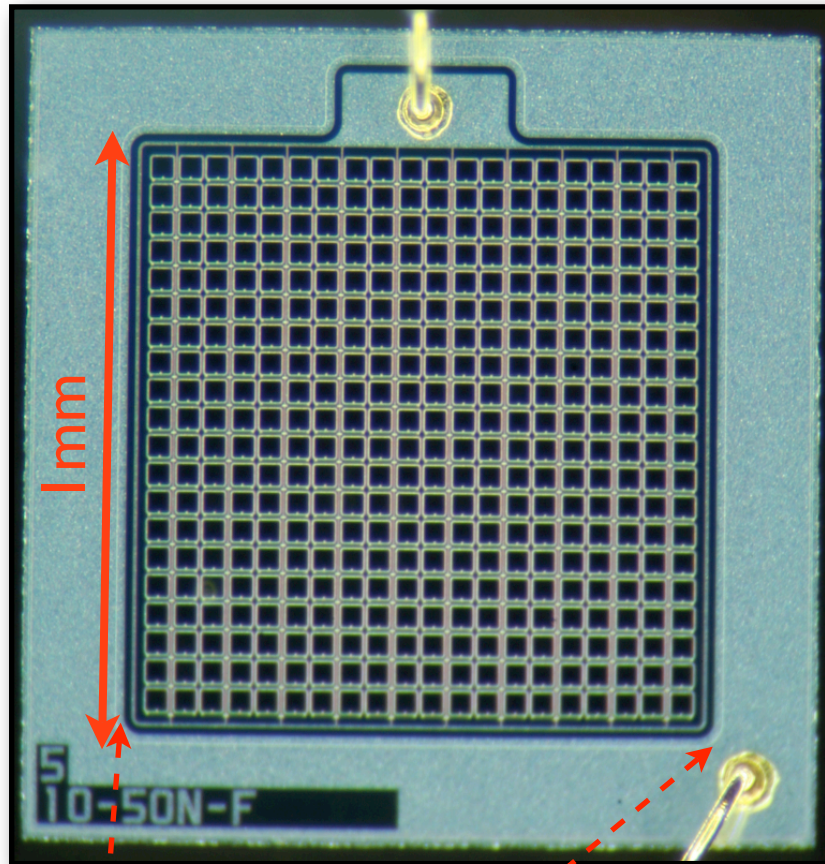
Highly Granular Hadronic Calorimeter

- Sandwich Calorimeter 38 Layers Steel / Plastic Scintillator Tiles
- ≈ 7600 Tiles with SiPM readout
- Several SiPM producers and sensor types on the market
- Future: Different Tile geometrics and readout schemes possible
- Which ones are suitable?
 - ➔ Characterisation studies necessary



Silicon Photomultiplier (SiPM)

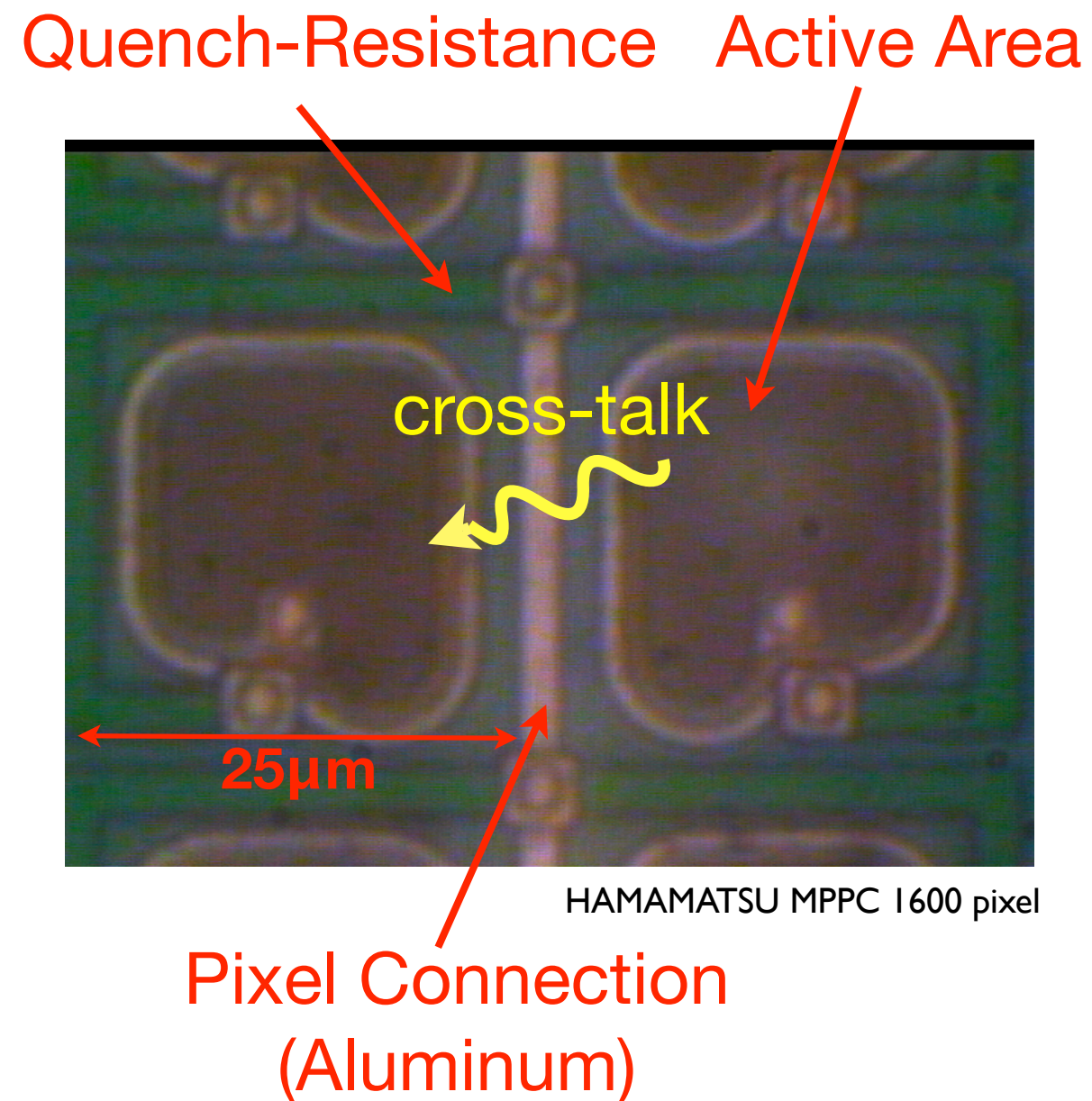
Geiger-Mode Avalanche-Photodiode GAPD, Pixelised Photon Detector PPD, Multi Pixel Photon Counter MPPC (HAMAMATSU)



- Geiger Mode ($U_{bias} > U_{break}$) \Rightarrow Binary device!
- Pixels signals are summed up \Rightarrow Linear response if $N_{photon} \ll N_{pixel}$

SiPM Properties

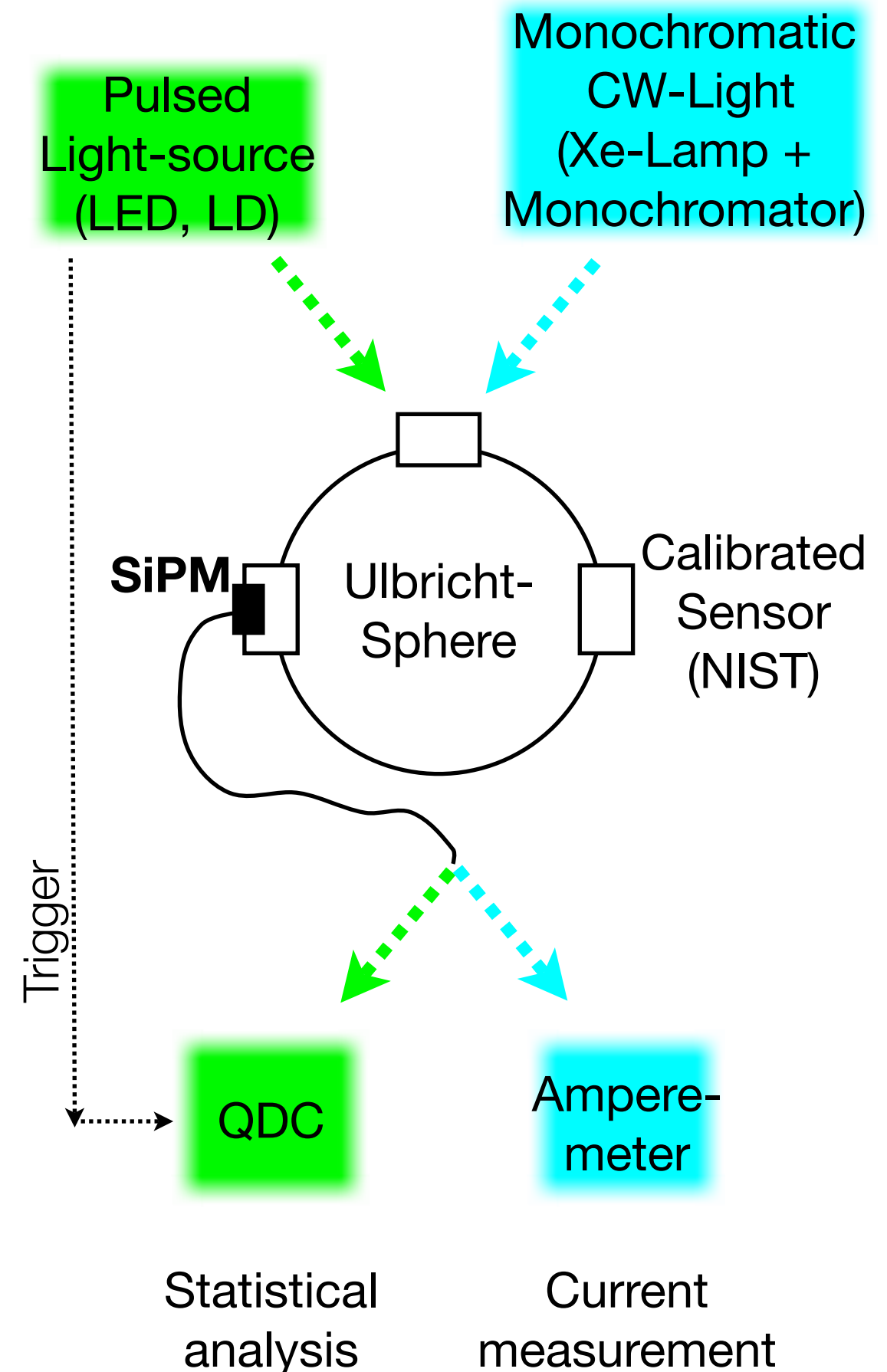
- High Gain $O(10^6)$
- Low operating voltage ($<100V$)
- Compact (few mm)
- Magnetic field insensitive
- But there are also **drawbacks**:
- **Optical cross-talk (CT)**
 3×10^{-5} photons per charge carrier traversing the junction
 $G=10^6 \Rightarrow 30$ photons ($E > 1.14eV$)
- **After-pulses (AP)**
Delayed Avalanche caused by trapped electrons



PDE Measurement

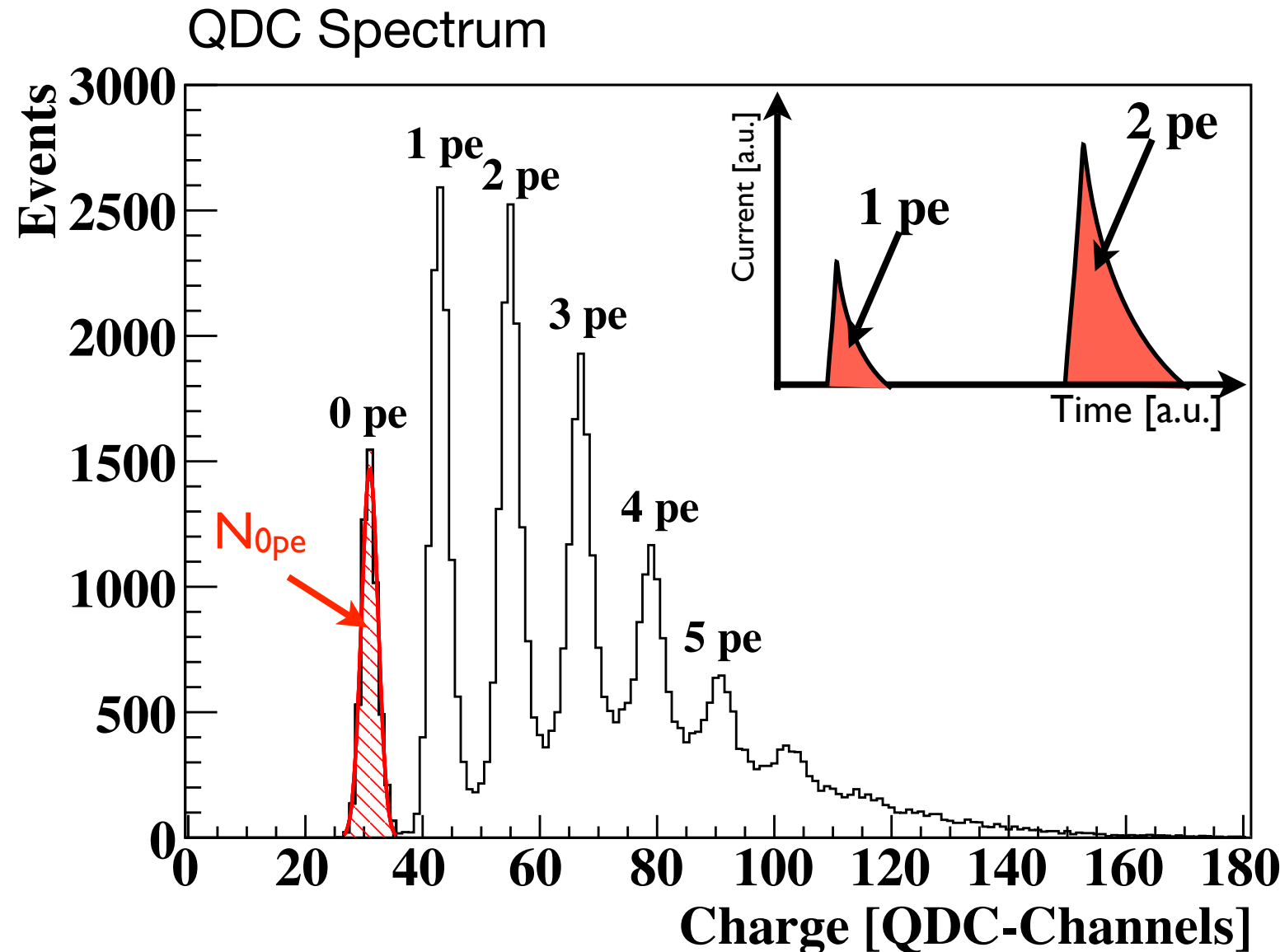
(KIP Heidelberg)

- Problem: Cross-talk and after-pulses cannot be separated from the photon induced signal
- **Statistical analysis method** allows to measure **absolute PDE** without CT and AP, but only for **individual λ** (i.e 465, 635, 775, 870nm)
- **Current measurement** allows to measure **relative PDE** over wide spectral range (**350-1000nm**), but contains CT and AP
- **Idea: Scaling of relative PDE**



Absolute PDE (Statistical Analysis)

- QDC readout is triggered independent from SiPM signal
- By measuring the number of times no photon was detected N_{0pe} , the average number of detected photons n_{pe} can be calculated (poisson dist.)
- Since N_{0pe} is not influenced by **CT** and **AP** (no pixel is firing), n_{pe} can be used to calculate the **absolute PDE**



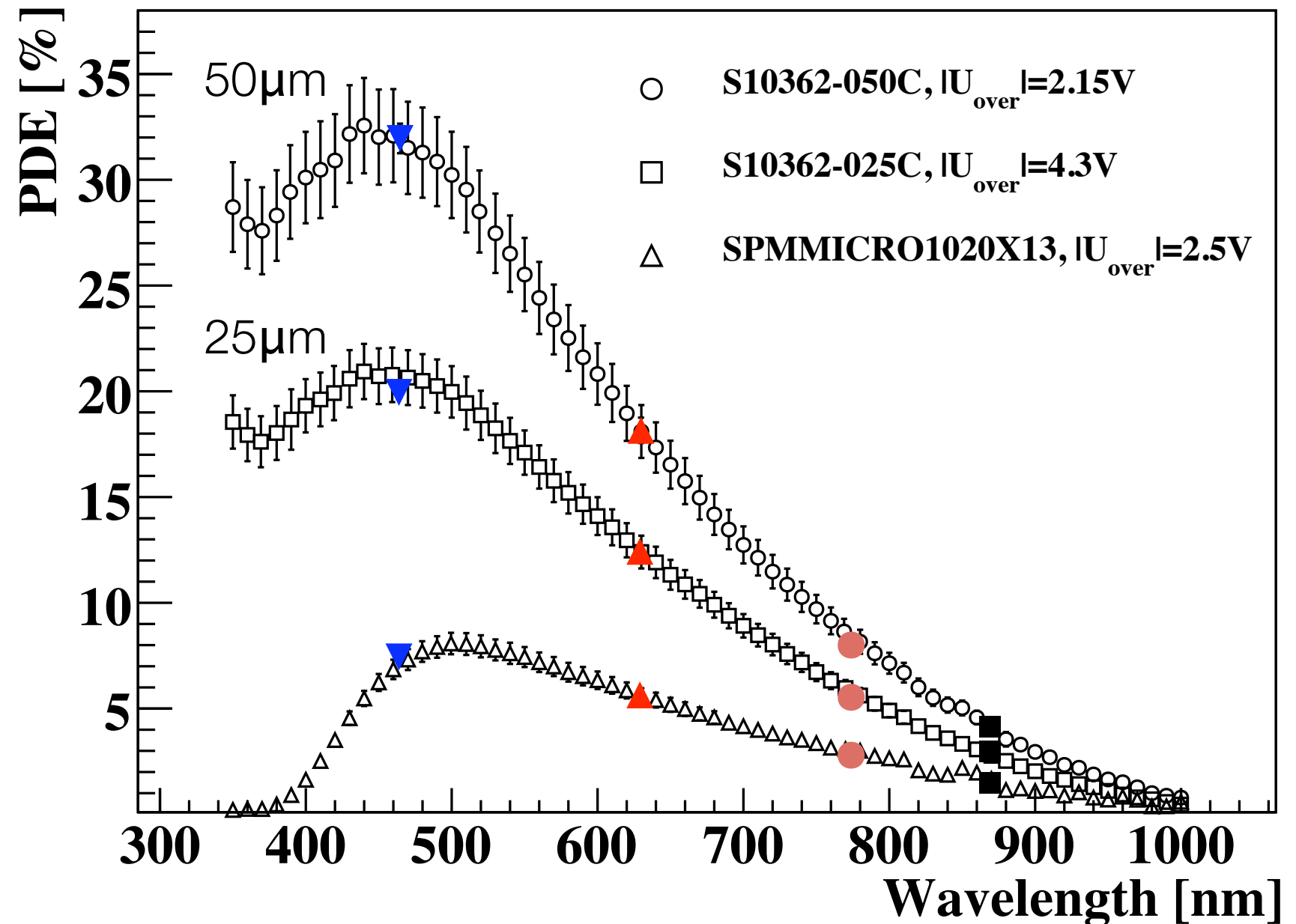
Poisson distribution:

$$P(n, n_{pe}) = \frac{n_{pe}^n \cdot e^{-n_{pe}}}{n!} \Rightarrow P(0, n_{pe}) = e^{-n_{pe}}$$

$$\Rightarrow n_{pe} = -\ln \left(\frac{N_{0pe}}{N_{Tot.}} \right)$$

PDE: Wavelength dependent

- Relative PDE curves have been scaled to the highest absolute PDE at 633nm.
- PDE values at 465, 775 and 870nm are in good agreement
➡ Consistency check
- MPPC: high PDE in blue region
- SensL SPM: more green sensitive

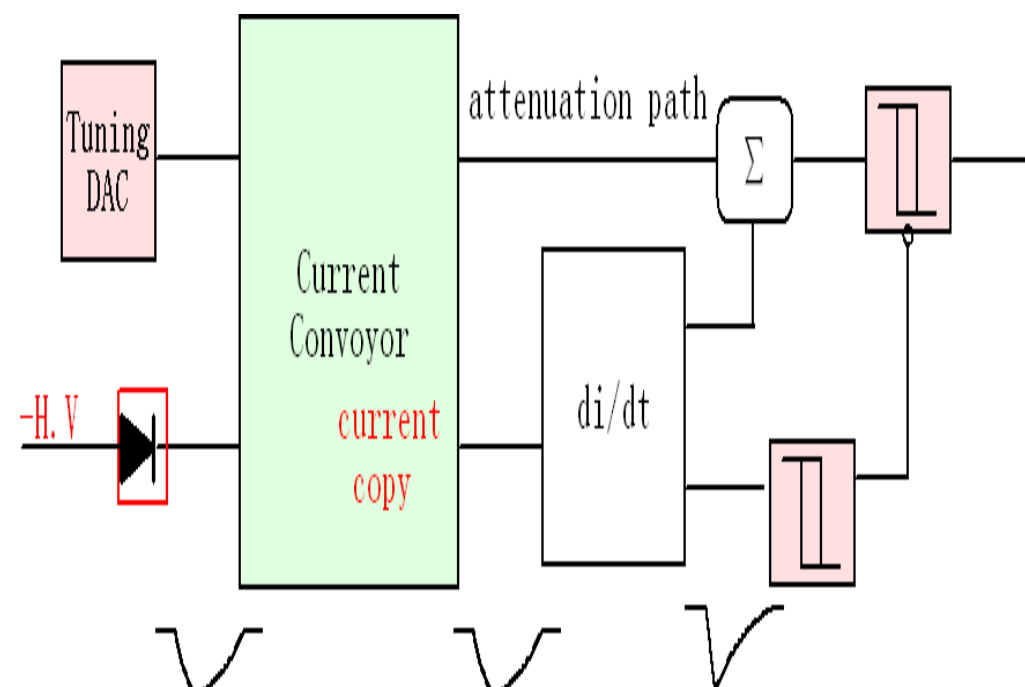
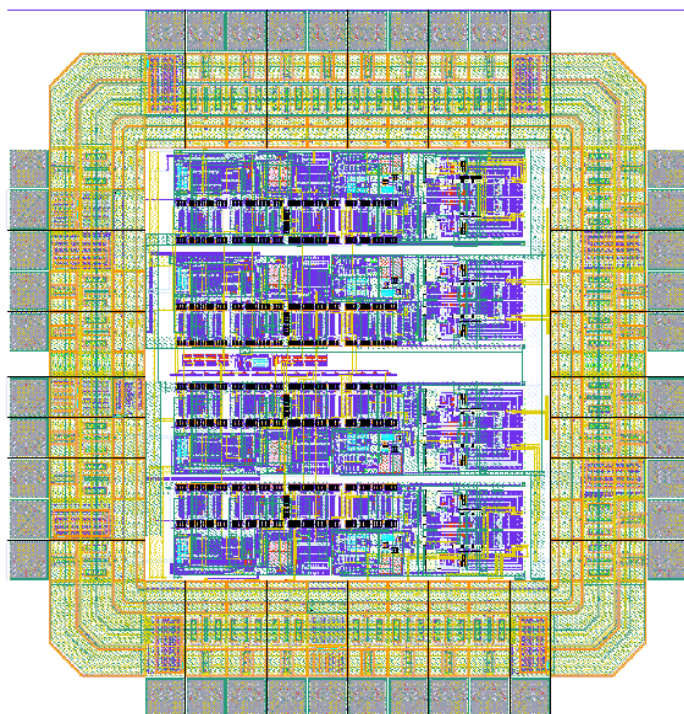
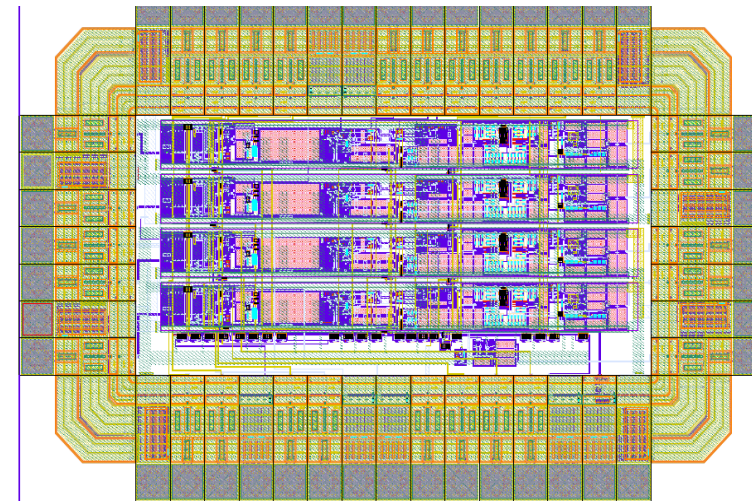
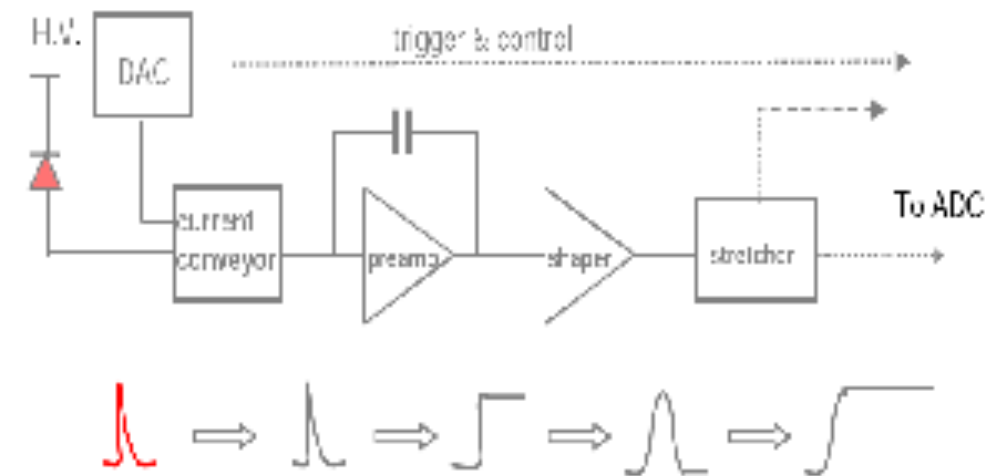


SiPM Readout Chip

(KIP Heidelberg)

SiPM charge sensitive readout

- tunable Sensor bias
- high signal to noise ratio
(>10 for SiPM gain = 2.5×10^5)
- fast trigger available for discrimination
- test chip with 4 channels
- Submitted in Oct. 2009
- AMS 0.35 μm CMOS



Fast Timing readout Chip

LVDS output
 Leading edge & CF triggering
 Time walk for 10:1 signal 80ps
 Time jitter $\sim 15\text{ps}$
 Power $< 10\text{ mW}$ / channel
 4 channels
 Submitted in Oct. 2009
 AMS 0.35 μm CMOS

Tile Coupling Study

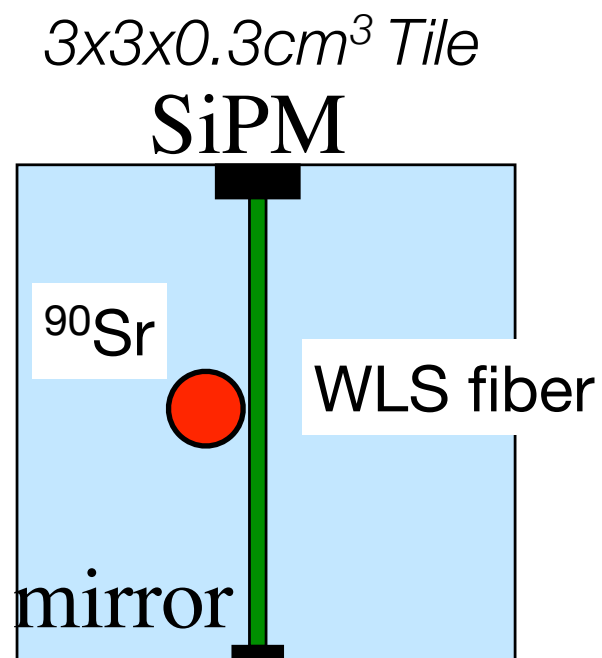
(DESY Hamburg)

- Wavelength shifting fiber vs. direct coupling (simpler assembly, cheaper)
- Source for Minimum ionizing particles (mips): ^{90}Sr
- Second tile with PMT readout used for trigger
- mip spectra recorded for different Tile-SiPM configurations
-> Most probable value (MPV)

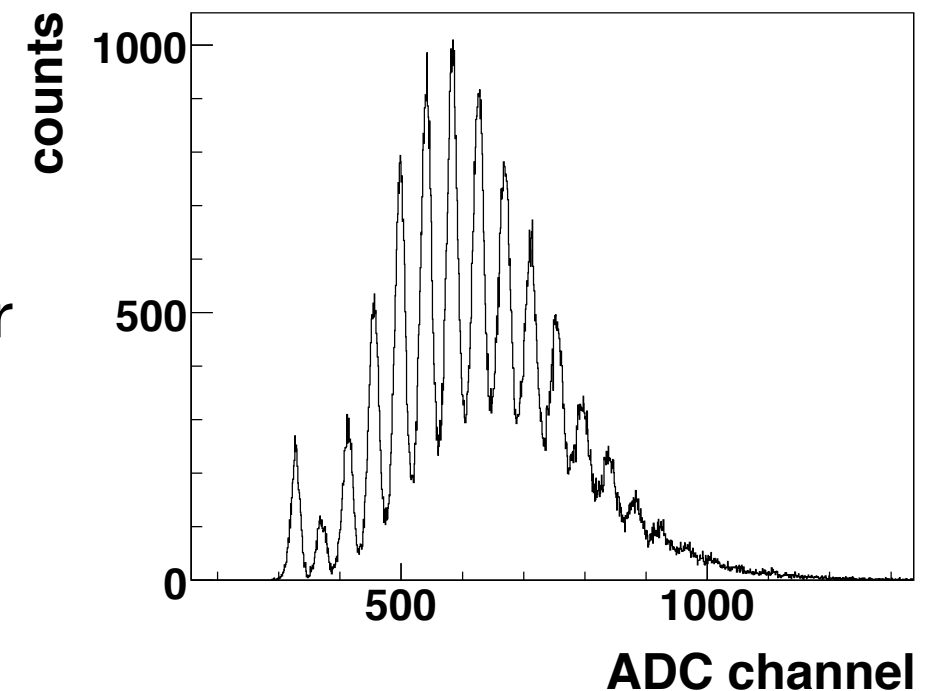
MPPCs used in study

# Pixels (size [mm ²])	Bias [V]	Dark Rate (0.5 p.e. threshold)	Pixel Size [μm ²]	Gain (10 ⁵)	PDE [%]
1600 (1x1)	70.4	200	25x25	2.5	25
3136 (1.4x1.4)	71.8	550 (200 kHz/mm ²)	25x25	2.5	25
400 (1x1)	69.4	600	50x50	7.5	50
676 (1.3x1.3)	70.5	900 (530 kHz/mm ²)	50x50	7.5	50

Contains CT and AP

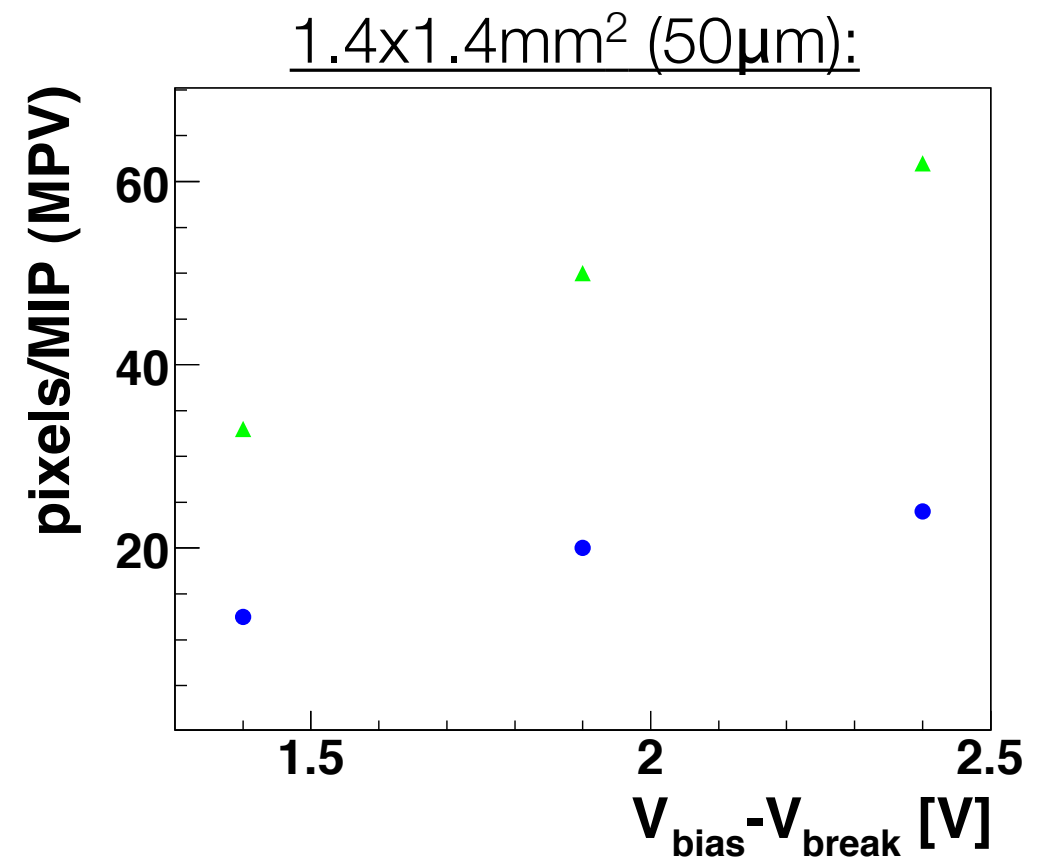
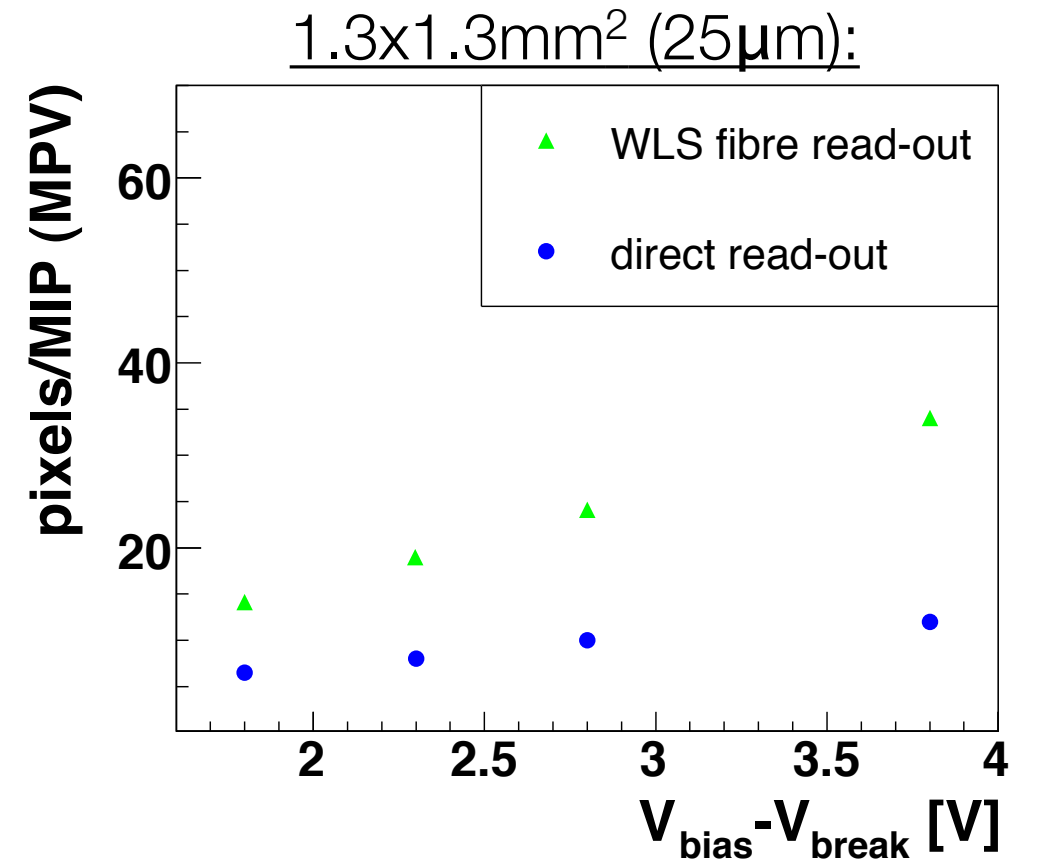
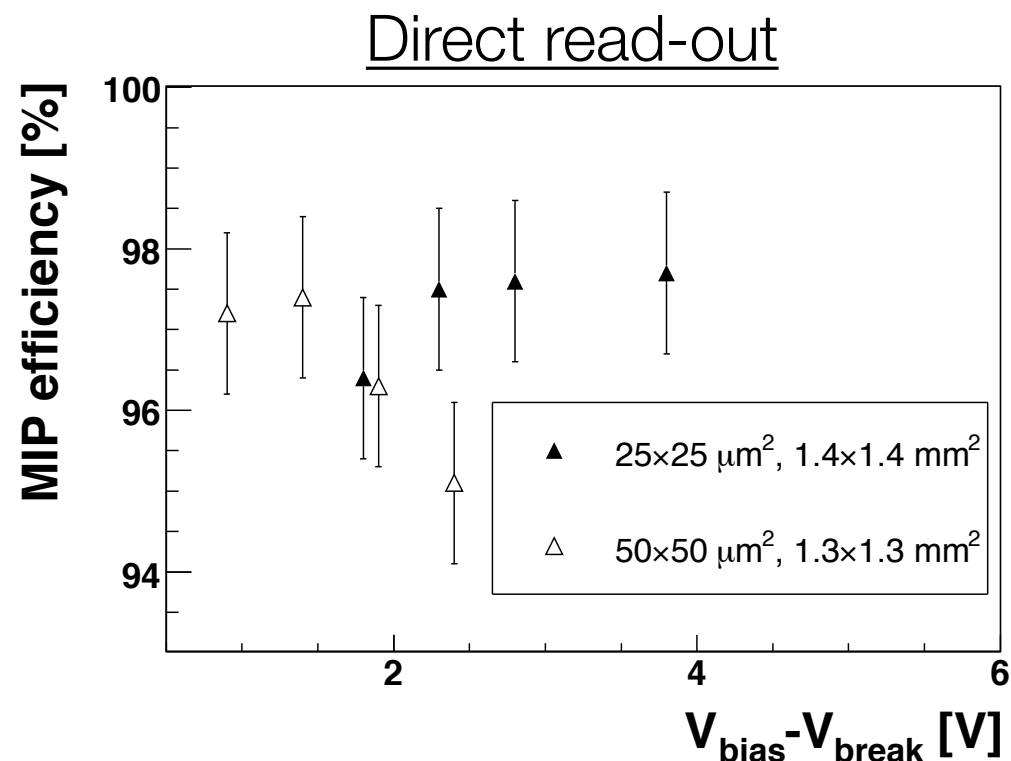


Typical mip spectrum



Tile Coupling: Results

- 25 μm and 50 μm Devices well suited
- Higher MPV for WLS fibre readout, but direct readout results also sufficient
- Mip detection efficiency higher than 95% for all configurations



Fiberless Readout of Scintillator Tiles

(MPI for Physics & Excellence Cluster 'Universe', Munich)

Blue sensitive SiPMs do not require a WLS fiber for readout

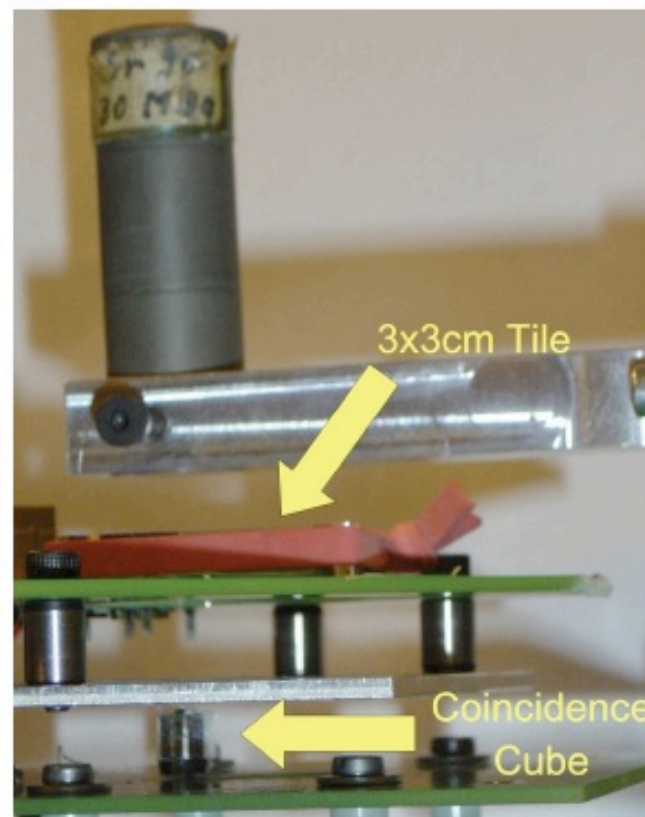
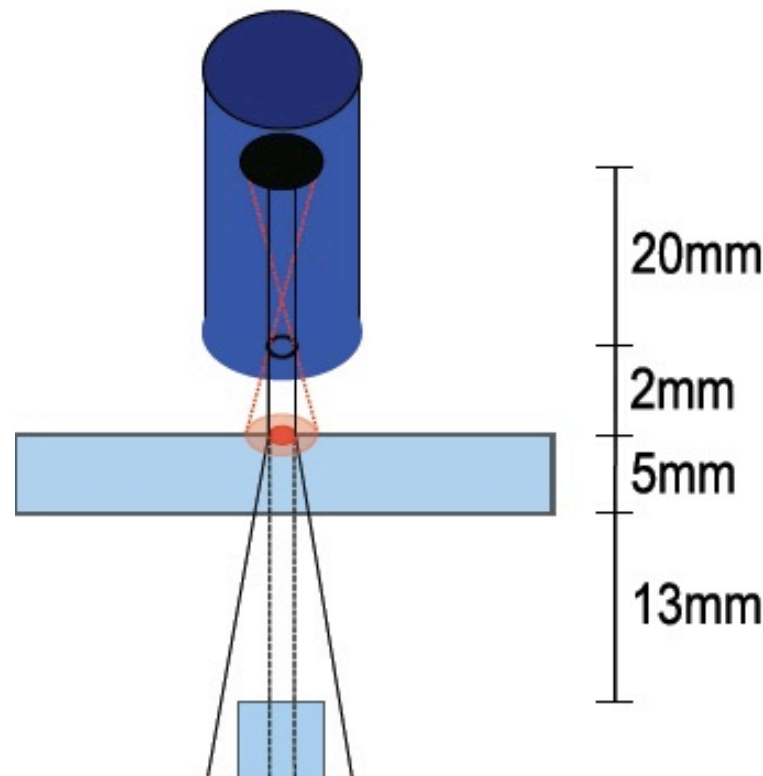
- Advantages:

- Simplified mechanics, alignment of SiPM
- Faster response: No spreading of pulse due to WLS absorption and reemission

- Drawback:

- WLS fiber collects light and guides it to the SiPM: improves uniformity!

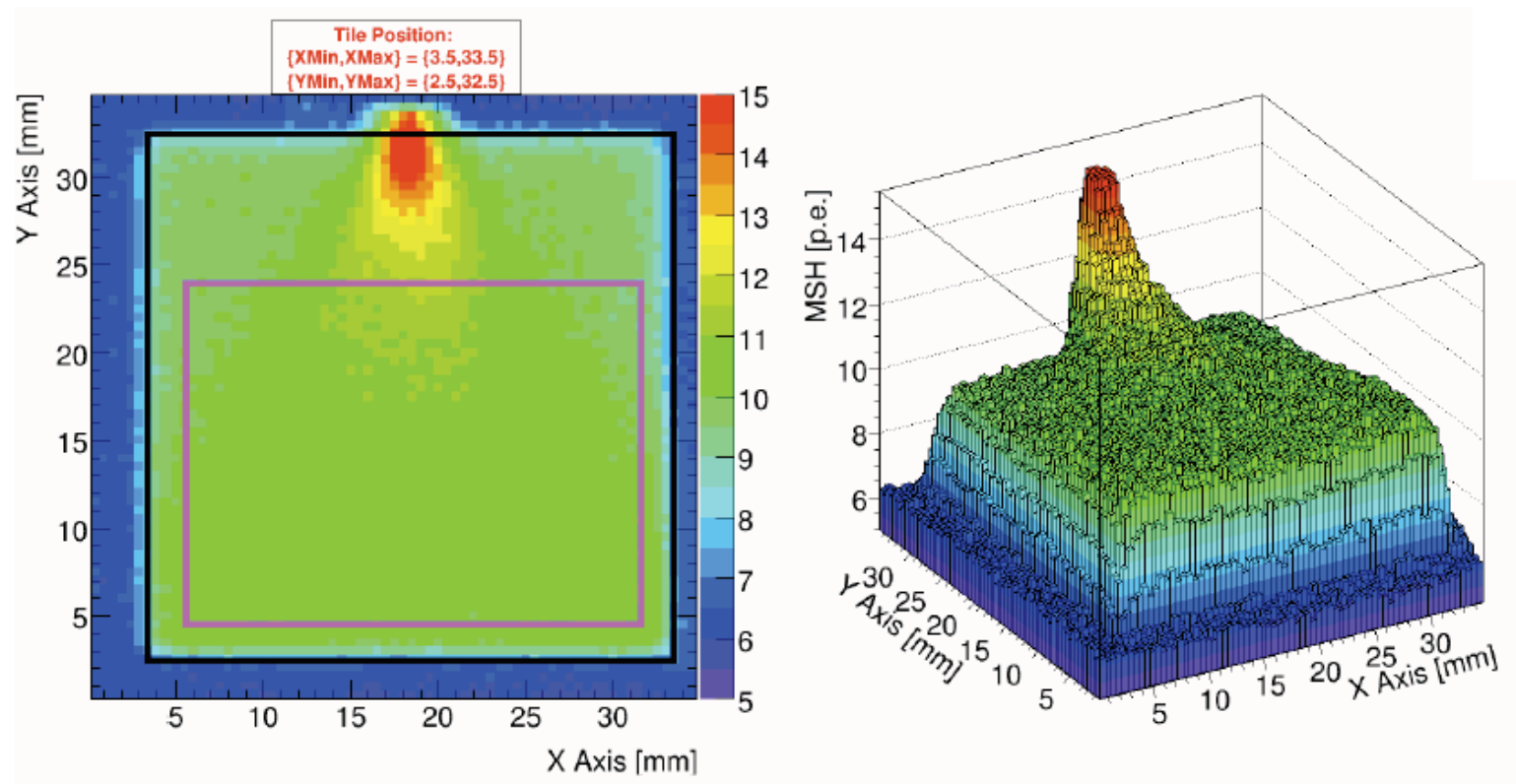
⇒ Optimize tile geometry to improve uniformity



A scanning setup with a ^{90}Sr source and a coincidence trigger for detailed mapping of the response of scintillator tiles has been constructed at MPI Munich

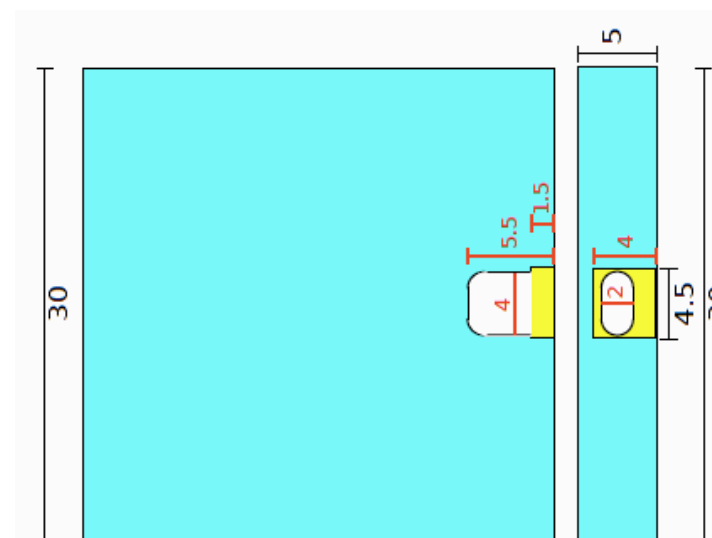
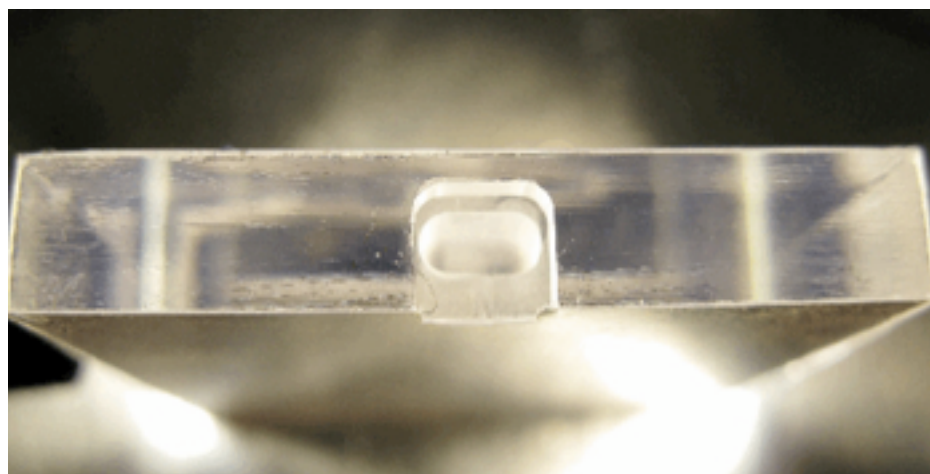
About 50 different tile geometries have been investigated

Direct Coupling: Non-Uniformity



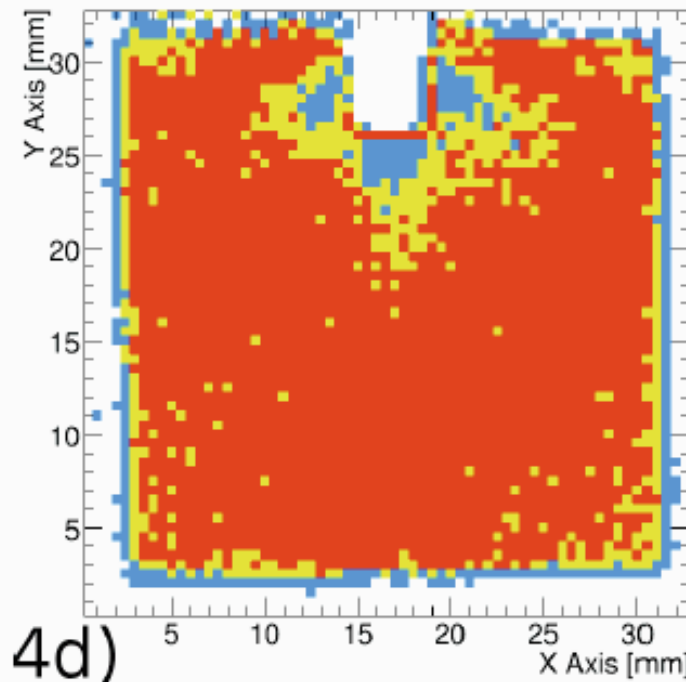
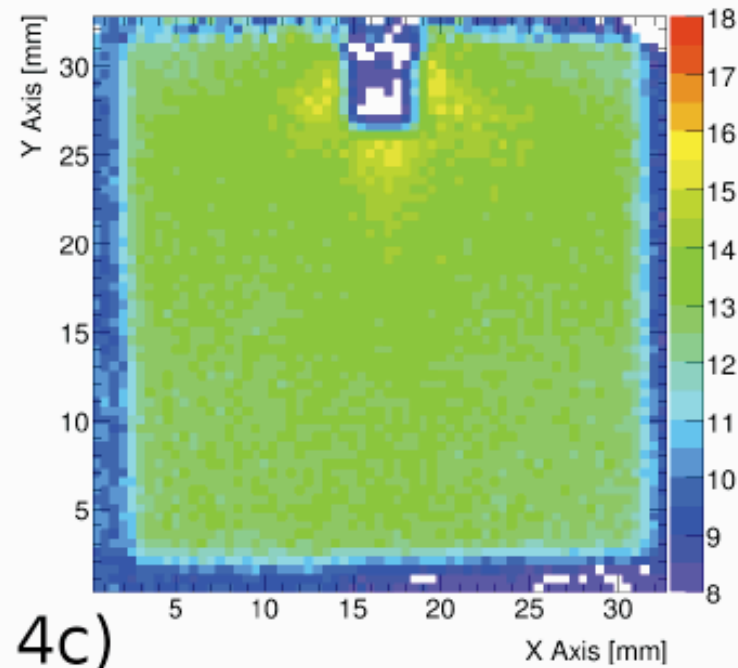
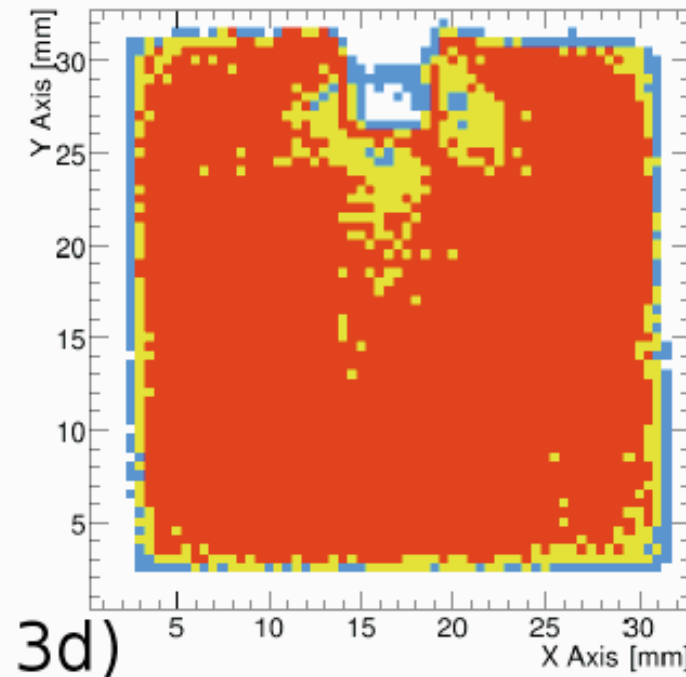
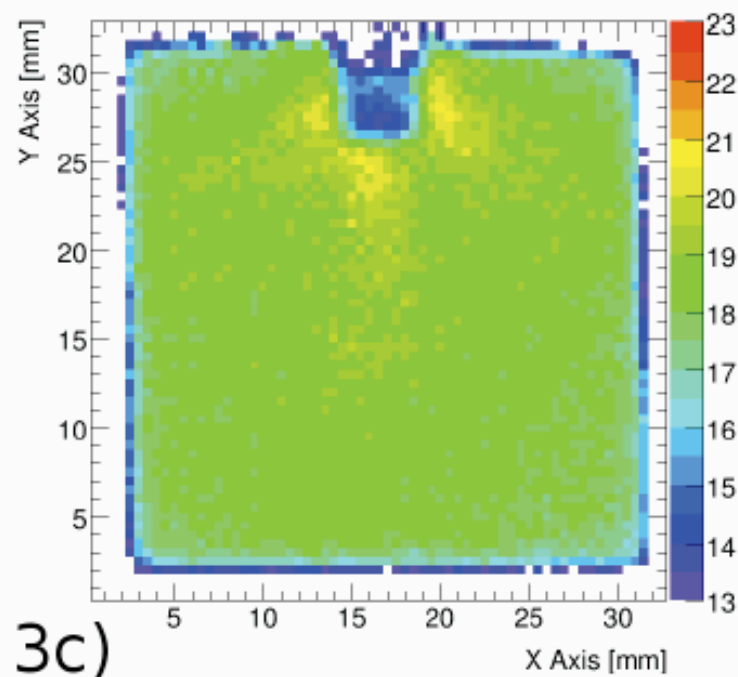
Strong non-uniformity,
significantly increased
response close to SiPM
coupling position

➡ The strategy: reduce material close to coupling position, improve light collection through embedding of SiPM and light diffusion



Add a “dimple” at the
SiPM coupling position:
Drilled into the tile

Improved Uniformity



4 x 2 mm² slit,
4 mm deep, SiPM
embedded
(1.5 mm deep)
mean signal 18.4 pe

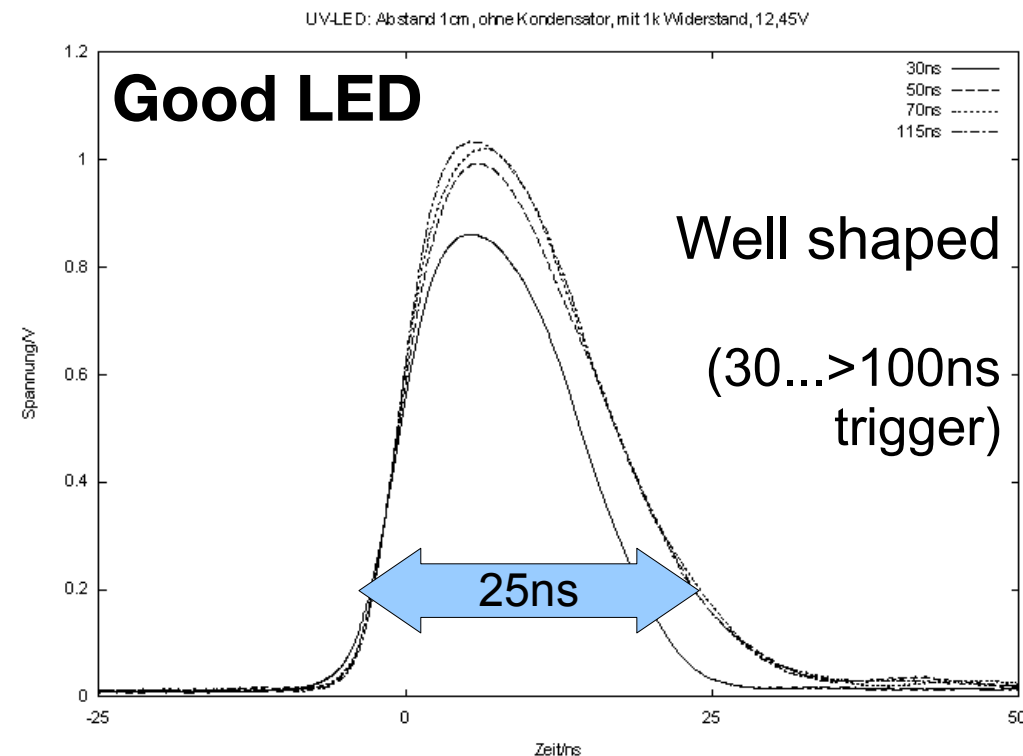
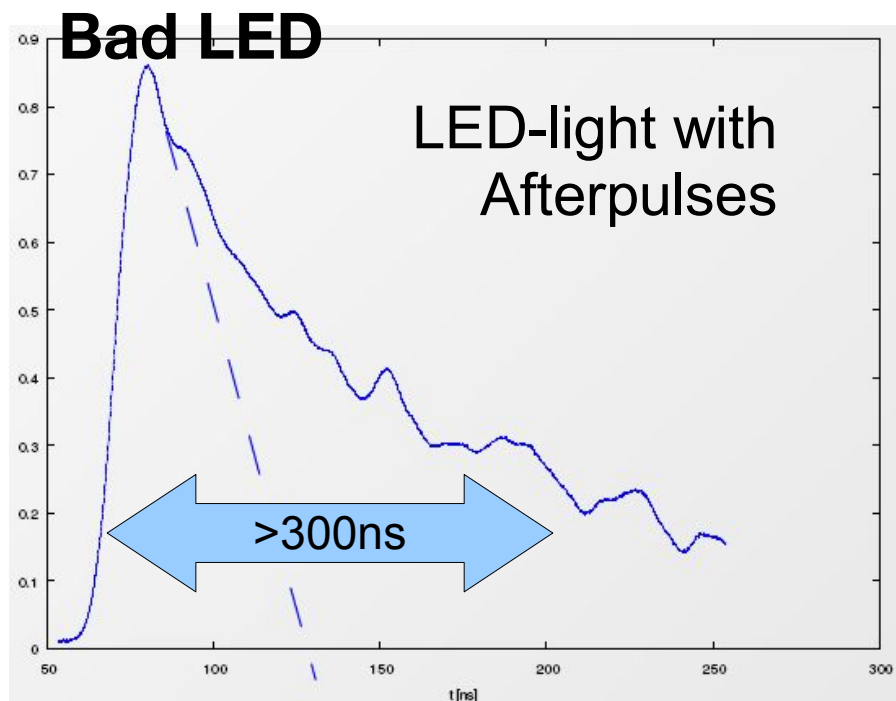
Typically
5%: ~72%
10%: ~84%

3 mm thick tile!
4 x 2 mm² slit,
4 mm deep, SiPM
embedded
(1.5 mm deep)
mean signal 13.2 pe

Embedded LED calibration system

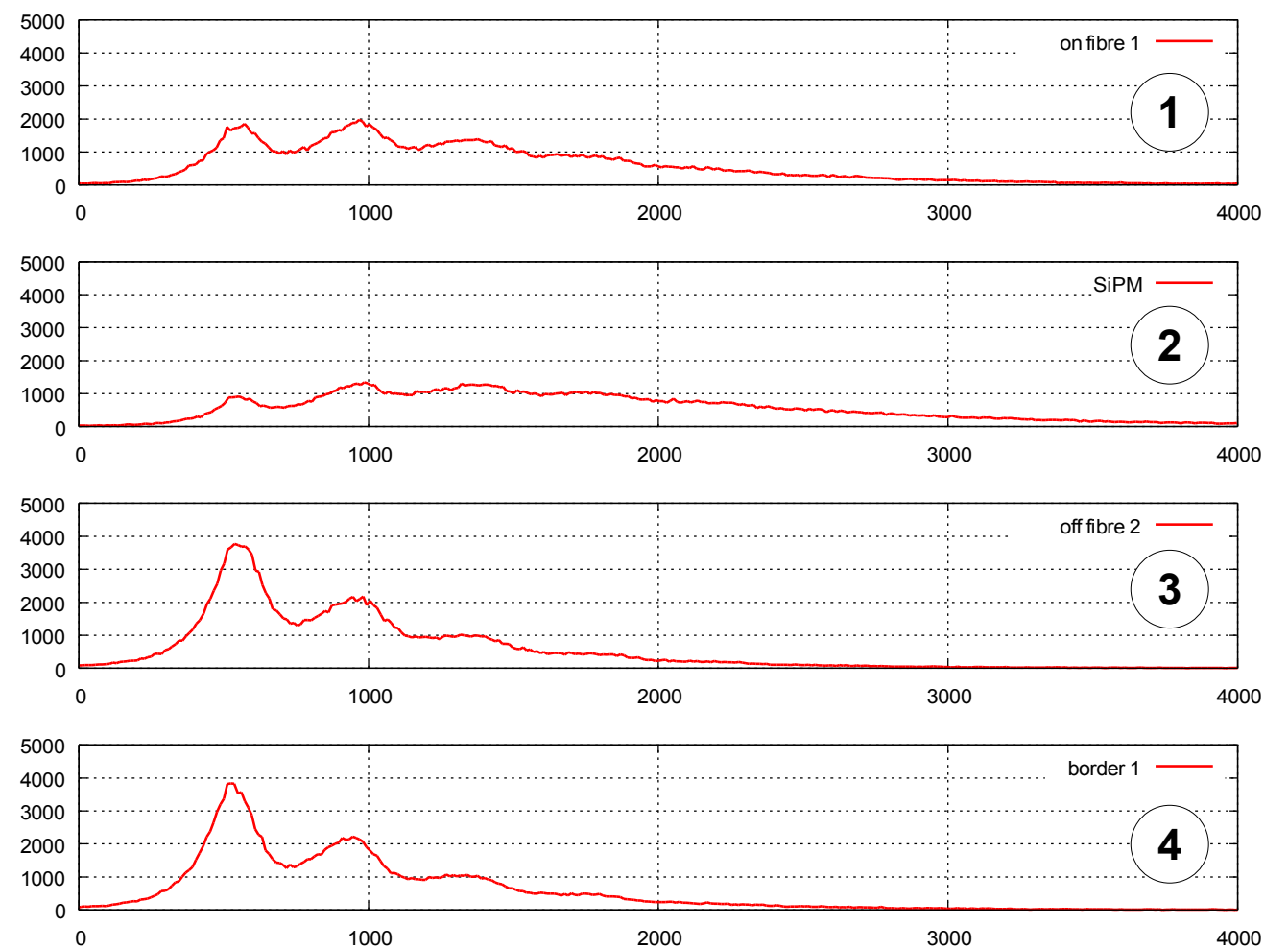
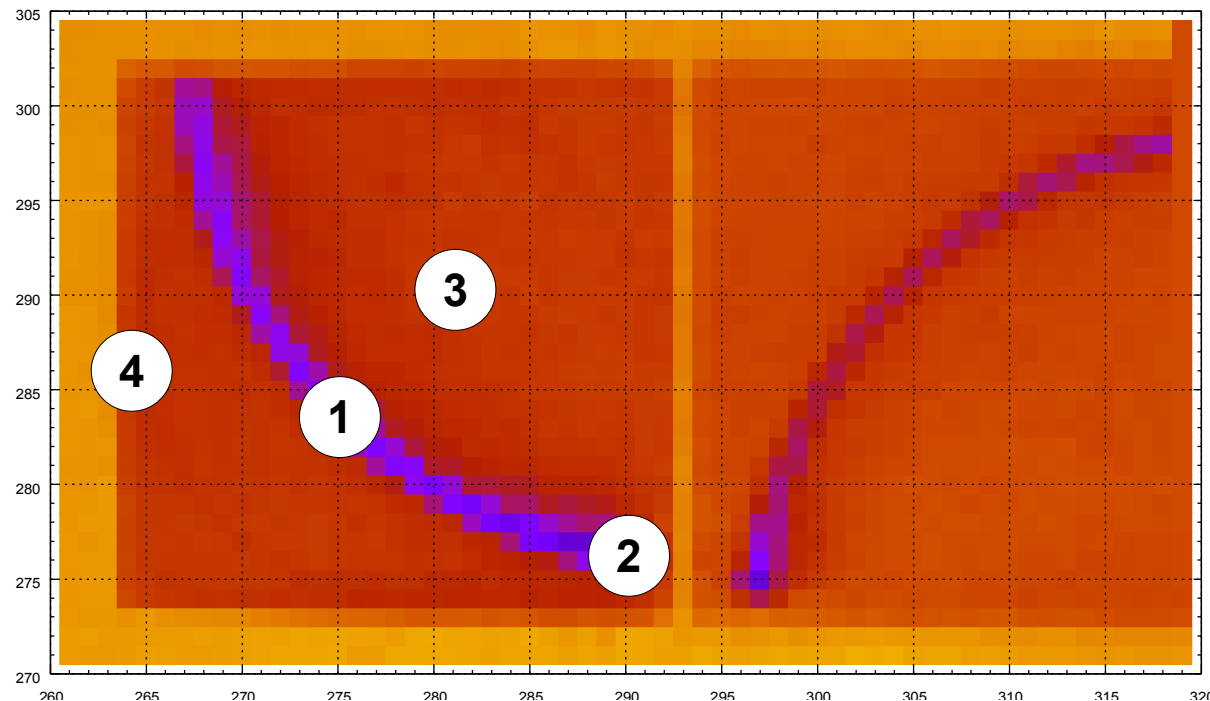
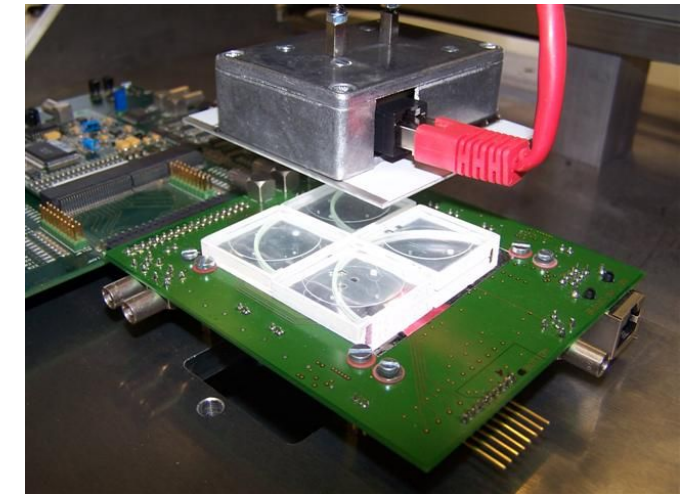
(Uni Wuppertal)

- One LED plus driver placed over each AHCAL tile, triggered by dedicated signal
- Driving circuit has been optimized to match needs of single photon spectra
 - Sharp, well shaped light pulse
 - Independence of trigger signal length
- Several LEDs of different type, color and manufacturer tested
- Most suitable, some show undesirable behaviour (afterpulsing)
 - **Blue LEDs work fine!**



LED Position

- XY stage to place LED on HCAL tiles
- Quickly exchangeable LED&Driver PCB
- Surface scan shows structure of tiles
- Fiber shows gain of ~ 2 in SiPM-signal, but also more noise (LED over SiPM: ~ 3)
- In the future: scans with Sr90



Conclusion

- Test stand for essential SiPM characterisation
 - ▢▢▢▢▢ PDE, Cross-talk, After-pulse probabilities ...
- SiPM readout chip submitted in october
- Detailed tile coupling studies covering SiPM selection and tile geometry have been performed
- First results on embedded LED calibration system

Backup Slides

PDE: Voltage Dependent

- QDC spectra recorded and evaluated for a range of bias voltages
- Highest PDE value at 635nm is used in the next step scaling.

$$\text{PDE} = \frac{N_{\text{SiPM}}}{N_{\text{Photon}}} = \frac{n_{\text{pe}}}{P_{\text{opt}} \cdot T / (R_{0.6} \cdot h \cdot \frac{c}{\lambda})}$$

n_{pe} : Photoelectrons per light-pulse

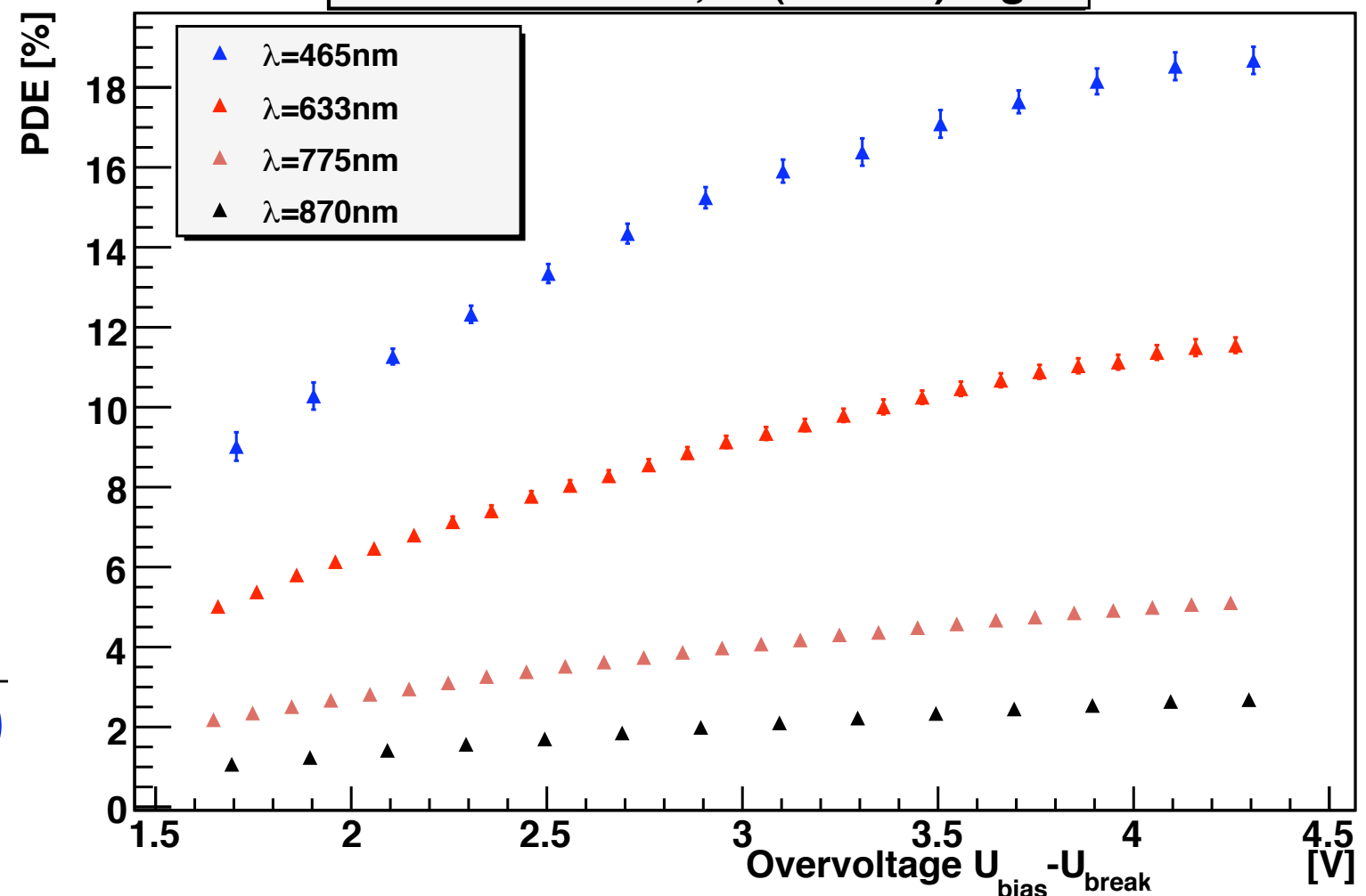
T : Light-pulse period

$R_{0.6}$: Power-ratio of sphere (Port1/Port2)

P_{opt} : Optical power measured by calibrated sensor

Example: HAMAMATSU MPPC 25 μm

S10362-11-025C, T=(25 \pm 1.5)degC



Temperature dependency

- XY-stage placed in temperature controlled environment
- Studies of temperature dependencies over wide range possible

- Gain 0...38°C:
 - Measure peak distance
 - Almost linear as expected (8.9 counts/K \rightarrow 2.1%/K)

